



# DCR2860C22

# **Phase Control Thyristor**

Replaces DS5818-3 DS5818-4 August 2023 (LN42766)

### **FEATURES**

- Double Side Cooling
- High Surge Capability

### **APPLICATIONS**

- High Power Drives
- High Voltage Power Supplies
- Static Switches

## **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages VDRM and VRRM (V)	Conditions
DCR2860C22 DCR2860C20 DCR2860C18	2200 2000 1800	$T_{vj}$ = -40°C to 125°C, IDRM = $IRRM$ = 200mA, $VDRM$ , $VRRM$ $t_p$ = 10ms VDSM & $VRSM$ = VDRM & $VRRM$ + 100V respectively

Lower voltage grades available.

## **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

## DCR2860C22

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

### **KEY PARAMETERS**

$\mathbf{V}_{DRM}$	2200V
I <sub>T(AV)</sub>	2860A
Ітѕм	38000A
dV/dt*	1500V/µs
dI/dt	400A/μs

<sup>\*</sup> Higher dV/dt selections are available on request

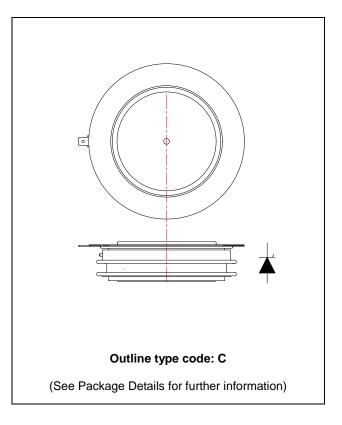


Fig. 1 Package outline

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## **CURRENT RATINGS**

## T<sub>case</sub> = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
IT(AV)	Mean on-state current	Half wave resistive load	2860	А
IT(RMS)	RMS value	-	4490	А
lτ	Continuous (direct) on-state current	-	4220	Α

## **SURGE RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
Ітѕм	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 125°C	38.0	kA
l²t	I2t for fusing	V <sub>R</sub> = 0	7.22	MA <sup>2</sup> s

## THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
		Double side cooled	DC	-	10.1	°C/kW
Rth(j-c)	Thermal resistance - junction to case		Anode DC	-	17.6	°C/kW
		Single side cooled	Cathode DC	-	23.9	°C/kW
D	The second are interest on the state in both i	Clamping force 37kN	Double side	-	2.5	°C/kW
Rth(c-h)	Thermal resistance - case to heatsink	(with mounting compound)	Single side	-	5.0	°C/kW
Tvj	Virtual junction temperature	Blocking VDRM / VRRM		-	125	°C
Tstg	Storage temperature range			-55	125	°C
Fm	Clamping force			33	41	kN

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## **DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Test Condition	ns	Min.	Max.	Units
IRRM/IDRM	Peak reverse and off-state current	At VRRM/VDRM, Tcase = 125°C	;	-	200	mA
Vтм	Instantaneous forward voltage	At 4000A peak, Tj = 125°C		1.30	1.50	٧
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V <sub>DRM</sub> , T <sub>j</sub> = 125°C, g	ate open	-	1500	V/µs
dl/dt	Rate of rise of on-state current	From 67% VDRM to 2x IT(AV)	Repetitive 50Hz	-	200	A/µs
di/dt	Rate of fise of off-state current	Gate source 30V, $10\Omega$ tr < 0.5 $\mu$ s, Tj = 125°C	Non-repetitive	-	400	A/µs
V	Threshold voltage - Low level	500A to 2300A at Tcase = 125°C		-	0.81	V
<b>V</b> т(то)	T(TO) Threshold voltage - High level 2300A to 7000A at Tcase = 125°C		25°C	-	0.97	V
	On-state slope resistance - Low level	500A to 2300A at Tcase = 125°C		-	0.20	mΩ
ľΤ	On-state slope resistance - High level	2300A to 7000A at Tcase = 125°C		-	0.13	mΩ
tgd	Delay time	$V_D$ = 67% $V_{DRM}$ , gate source 30V, 10Ω $t_T$ = 0.5 $\mu$ s, $T_j$ = 25°C		-	3	μs
tq	Turn-off time	$T_j = 125$ °C, $V_R = 200$ V, $dI/dt = 1$ A/ $\mu$ s, $dV_{DR}/dt = 20$ V/ $\mu$ s linear		100	250	μs
Qs	Stored charge	Iτ = 2000A, Tj = 125°C, dl/dt = 1A/μs		200	1100	μC
Iι	Latching current	Tj = 25°C, VD = 5V		-	3	А
lн	Holding current	Tj = 25°C, Rg-к = ∞, Iтм = 50	0Α, Iτ = 5Α	-	300	mA

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## **GATE TRIGGER CHARACTERISTICS AND RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
<b>V</b> GT	Gate trigger voltage	VDRM = 5V, Tcase = 25°C	1.5	V
<b>V</b> GD	Gate non-trigger voltage	At 50% VDRM, Tcase = 125°C	0.4	V
lgт	Gate trigger current	VDRM = 5V, Tcase = 25°C	250	mA
IGD	Gate non-trigger current	At 50% VDRM, Tcase = 125°C	10	mA

## **CURVES**

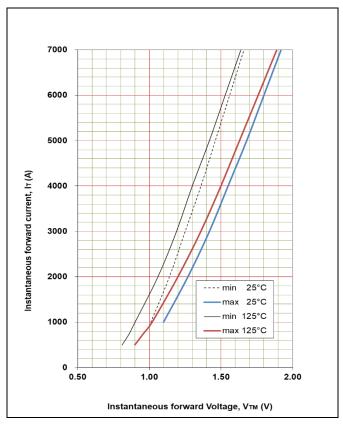


Fig. 2 Maximum & minimum on state characteristics

## **VTM EQUATION**

 $V_{TM} = A + B.ln(I_T) + C.I_T + D.\sqrt{I_T}$ 

Where A = 0.365315

B = 0.070220

C = 0.000104

D = 0.002063

These values are valid for  $T_j$  = 125°C for  $I_T$  500A to 7000A

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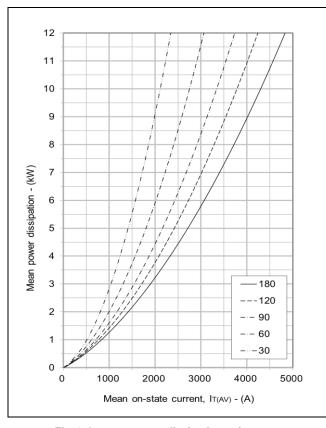


Fig. 3 On-state power dissipation - sine wave

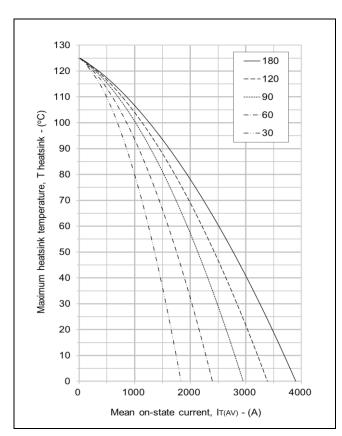


Fig. 5 Maximum permissible heatsink temperature, double side cooled - sine wave

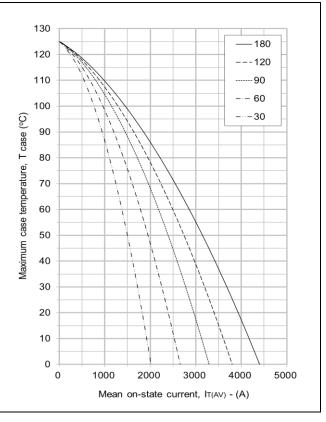


Fig. 4 Maximum permissible case temperature, double side cooled - sine wave

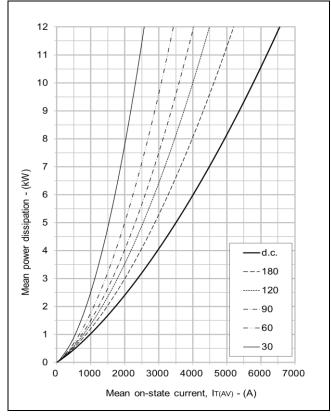


Fig. 6 On-state power dissipation - rectangular wave

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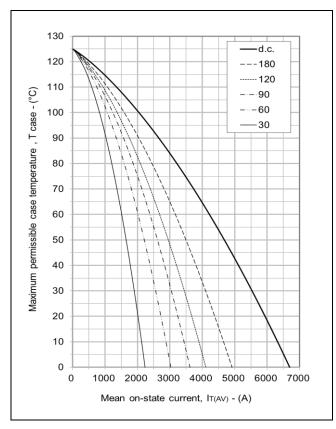
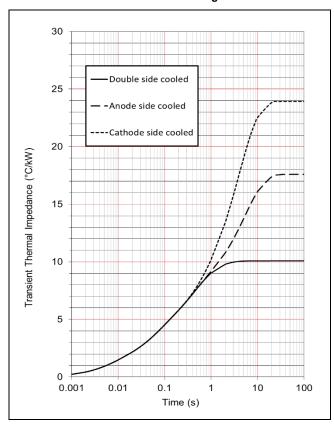


Fig. 7 Maximum permissible case temperature, double side cooled - rectangular wave



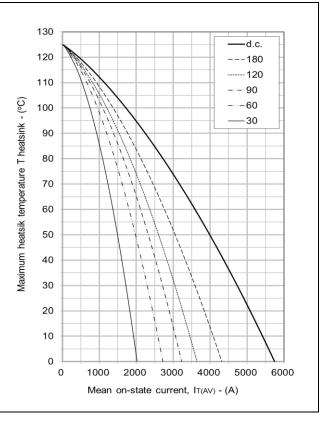


Fig. 8 Maximum permissible heatsink temperature, double side cooled - rectangular wave

		1	2	3	4
Double side	Ri(°C/kW)	1.104	2.576	4.510	1.901
cooled	Ti(s)	0.006	0.052	0.382	1.060
Anode side	Ri(°C/kW)	1.098	2.457	4.047	9.999
cooled	Ti(s)	0.006	0.050	0.313	5.270
Cathode side	Ri(°C/kW)	1.152	2.893	2.406	17.479
cooled	Ti(s)	0.006	0.058	0.378	3.970

$$Z_{th} = \sum_{i=1}^{i=4} R_i \cdot \left(1 - \exp\left(-\frac{T}{T_i}\right)\right)$$

 $\Delta R_{\text{th(j-c)}}$  Conduction

Tables show the increments of thermal resistance R  $_{\text{th}[j-c]}$  when the device operates at conduction angles other than d.c.

Double side cooling				
	$\Delta Z_{th}$ (	(z)		
θ°	sine.	rect.		
180	1.95	1.26		
120	2.32	1.89		
90	2.74	2.27		
60	3.14	2.70		
30	3.46	3.19		
15	3.61	3.47		

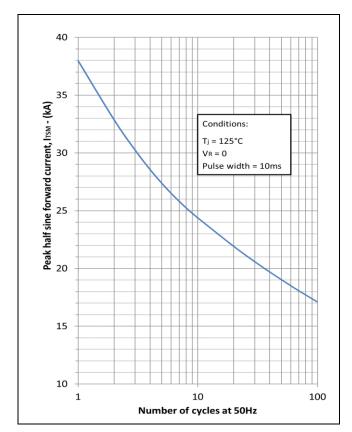
	Ariode Side	Cooling	
	$\Delta Z_{th}(z)$		
θ°	sine.	rect.	
180	1.95	1.26	
120	2.32	1.89	
90	2.74	2.27	
60	3.14	2.70	
30	3.46	3.19	
15	2.62	3.47	

Ca	thode Sided Cooling		
	$\Delta Z_t$	<sub>h</sub> (z)	
θ°	sine.	rect.	
180	1.95	1.26	
120	2.31	1.88	
90	2.72	2.26	
60	3.12	2.68	
30	3.43	3.17	
15	3.58	3.44	

Fig. 9 Maximum (limit) transient thermal impedance - junction to case (degC/kW)

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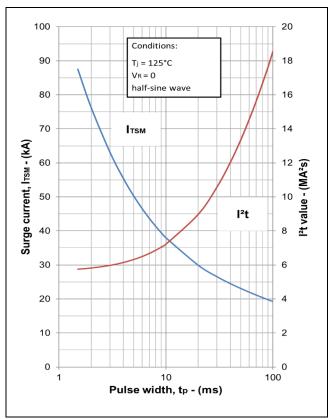


Fig. 10 Multi-cycle surge current

Fig. 11 Single-cycle surge current

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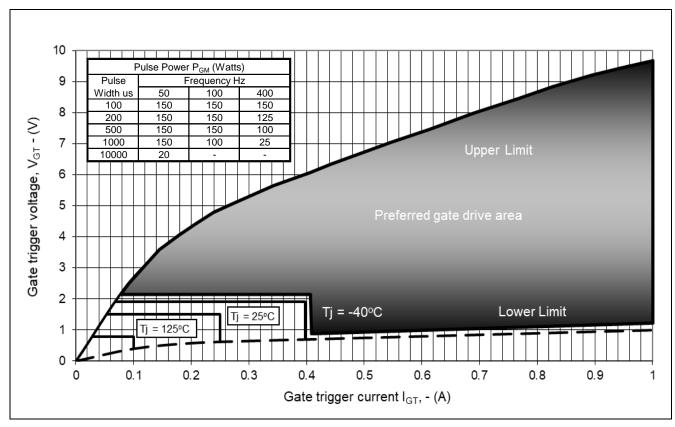


Fig. 14 Gate characteristics

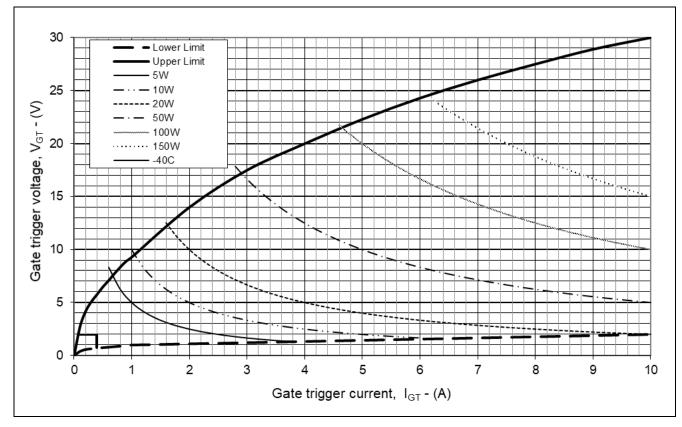


Fig. 15 Gate characteristics

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### **PACKAGE DETAILS**

For further package information, please contact Customer services.

All dimensions in mm, unless stated otherwise.

## DO NOT SCALE

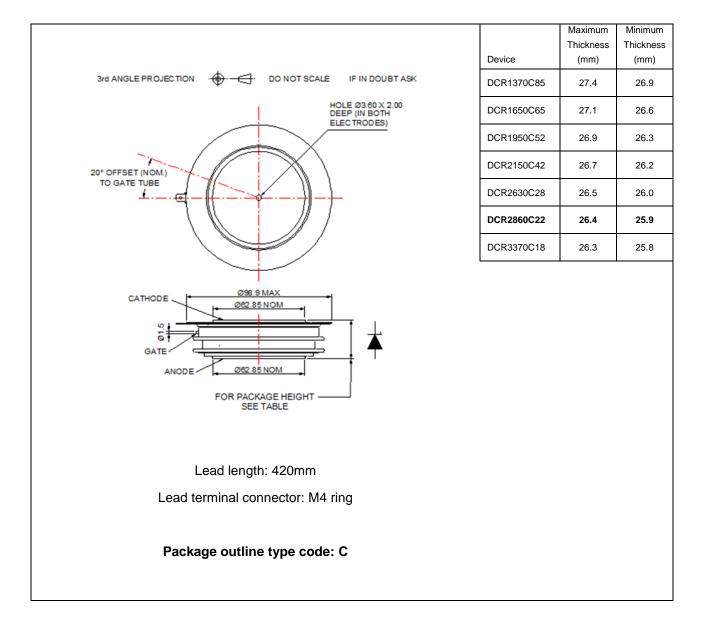


Fig. 16 Package outline

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